

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE60P50K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge .This device is well suited for high current load applications.

General Features

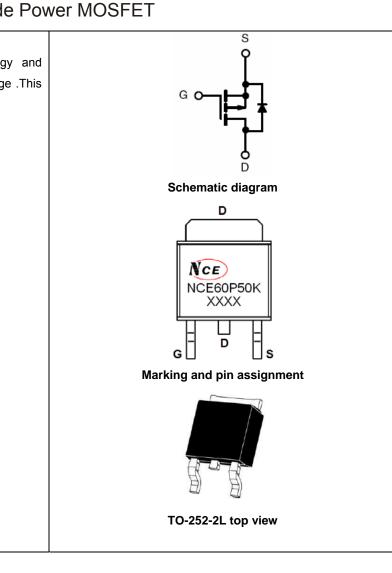
- V_{DS} =-60V,I_D =-50A
 R_{DS(ON)} <28mΩ @ V_{GS}=-10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

Application

Load switch

100% UIS TESTED!

100% ΔVds TESTED!



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE60P50K	NCE60P50K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	-50	А
Drain Current-Continuous(Tc=100℃)	I _D (100℃)	-35	A
Pulsed Drain Current	I _{DM}	-150	А
Maximum Power Dissipation	PD	95	W
Derating factor		0.76	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	722	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C



Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{ extsf{ heta}JC}$	1.31	°C /W

Electrical Characteristics (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250µA	-2.0	-2.6	-3.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-20A	-	23	28	mΩ
Forward Transconductance	g fs	V _{DS} =-10V,I _D =-20A	-	25	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C _{lss}		-	6460	-	PF
Output Capacitance	C _{oss}	V_{DS} =-25V, V_{GS} =0V,	-	719	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	535	-	PF
Switching Characteristics (Note 4)			1			I.
Turn-on Delay Time	t _{d(on)}		-	15	-	nS
Turn-on Rise Time	tr	V _{DD} =-30V, R _L =1.5Ω,	-	17	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-10V,R _G =3Ω	-	40	-	nS
Turn-Off Fall Time	t _f		-	45	-	nS
Total Gate Charge	Qg	N/ 001 001	-	75		nC
Gate-Source Charge	Q _{gs}	V_{DS} =-30,I _D =-20A,	-	16		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =-10V	-	19		nC
Drain-Source Diode Characteristics						I.
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-20A	-		-1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-50	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =-20A	-	50		nS
Reverse Recovery Charge	Qrr	di/dt = -100A/µs(Note3) - 59		nC		
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD				y LS+LD)

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

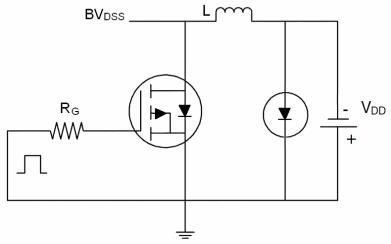
3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

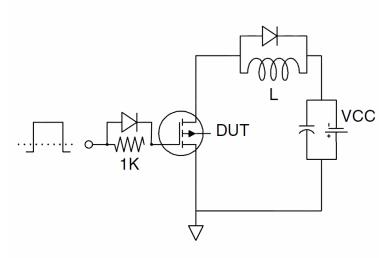
5. E_{AS} condition: Tj=25 °C, V_{DD} =-30V, V_{G} =-10V, L=1mH, Rg=25 Ω



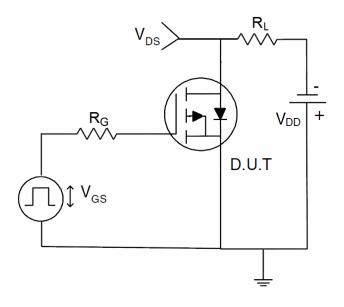
Test Circuit 1) E_{AS} Test Circuit



2) Gate Charge Test Circuit

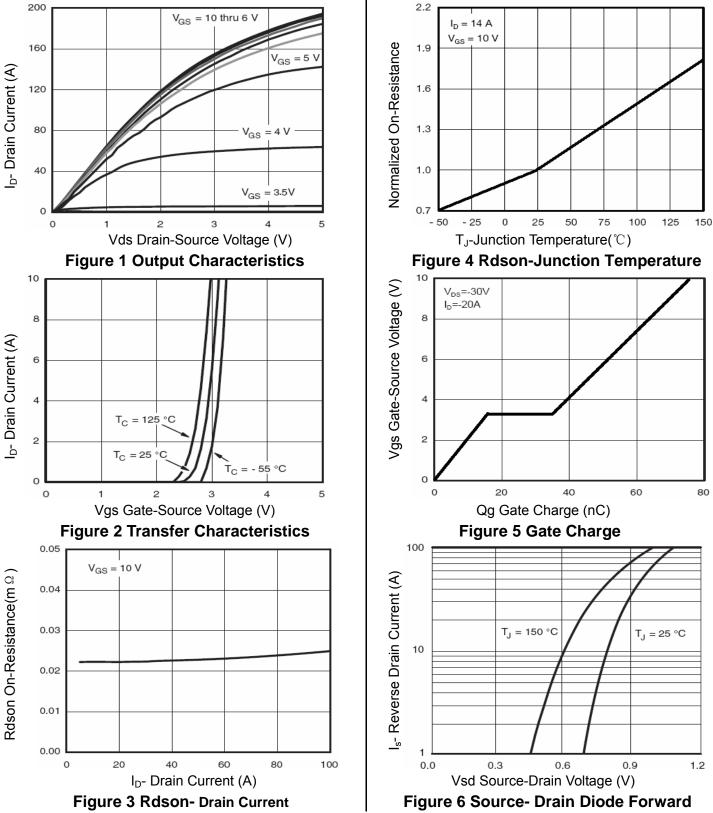


3) Switch Time Test Circuit











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NCE60P50K

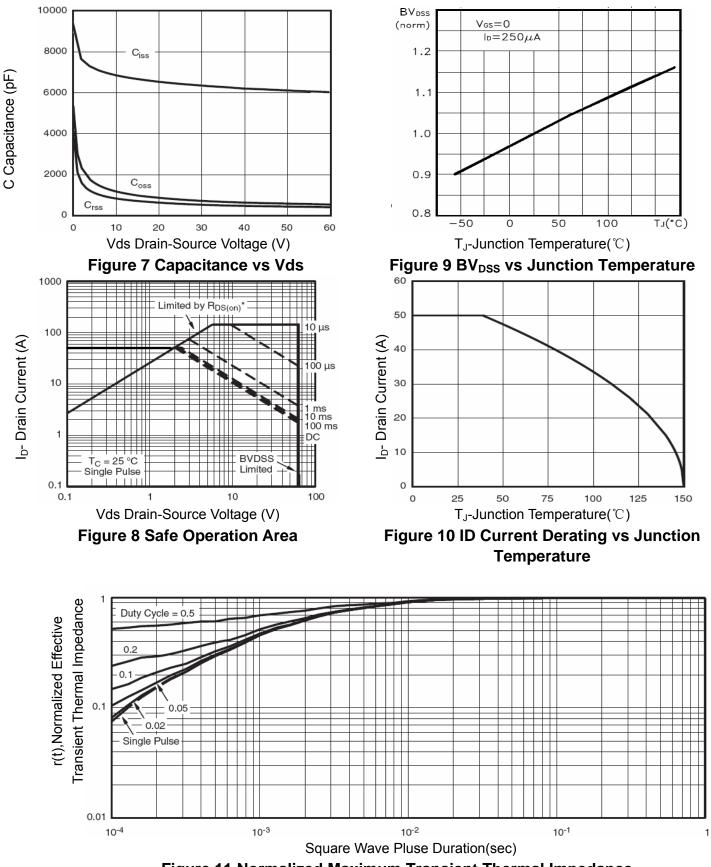
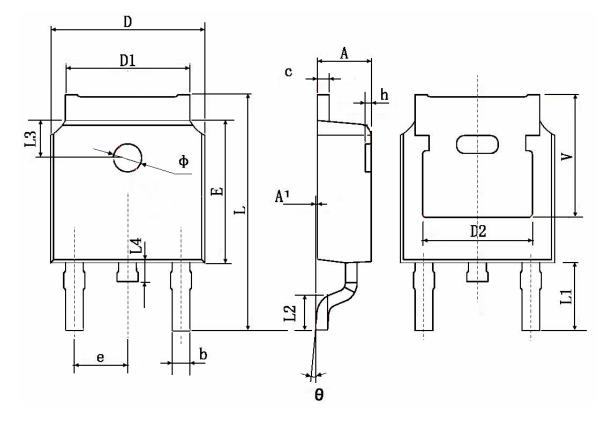


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252 Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.48	3 TYP.	0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.35	5.350 TYP. 0.211 TYP.			



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